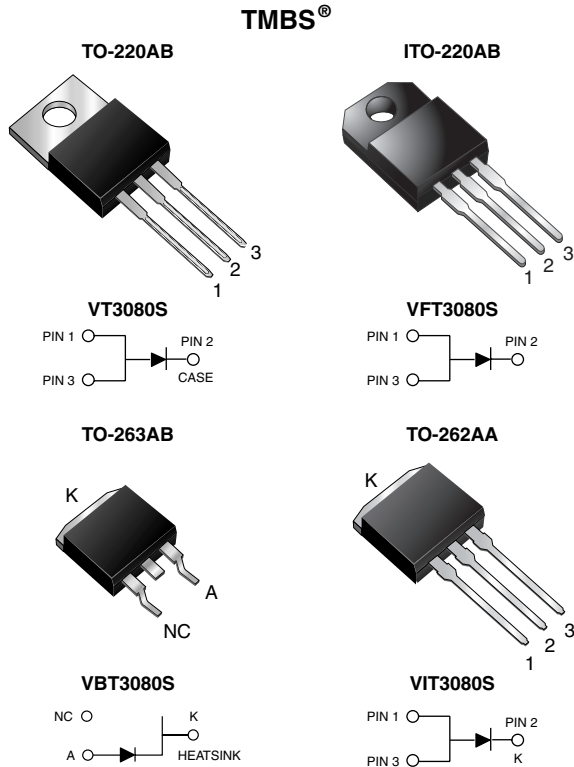


## Trench MOS Barrier Schottky Rectifier

Ultra Low  $V_F = 0.39\text{ V}$  at  $I_F = 5\text{ A}$



### FEATURES

- Trench MOS Schottky technology
- Low forward voltage drop, low power losses
- High efficiency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C (for TO-263AB package)
- Solder bath temperature 275 °C maximum, 10 s, per JESD 22-B106 (for TO-220AB, ITO-220AB, and TO-262AA package)
- Compliant to RoHS directive 2002/95/EC and in accordance to WEEE 2002/96/EC



**RoHS**  
COMPLIANT

### TYPICAL APPLICATIONS

For use in high frequency converters, switching power supplies, freewheeling diodes, OR-ing diode, dc-to-dc converters and reverse battery protection.

### MECHANICAL DATA

**Case:** TO-220AB, ITO-220AB, TO-263AB and TO-262AA

Molding compound meets UL 94 V-0 flammability rating  
Base P/N-E3 - RoHS compliant, commercial grade

**Terminals:** Matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

E3 suffix meets JESD 201 class 1A whisker test

**Polarity:** As marked

**Mounting Torque:** 10 in-lbs maximum

### PRIMARY CHARACTERISTICS

$I_{F(AV)}$	30 A
$V_{RRM}$	80 V
$I_{FSM}$	200 A
$V_F$ at $I_F = 30\text{ A}$	0.73 V
$T_J$ max.	150 °C

### MAXIMUM RATINGS ( $T_A = 25\text{ °C}$ unless otherwise noted)

PARAMETER	SYMBOL	VT3080S	VFT3080S	VBT3080S	VIT3080S	UNIT
Maximum repetitive peak reverse voltage	$V_{RRM}$			80		V
Maximum average forward rectified current (fig. 1)	$I_{F(AV)}$		30			A
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load	$I_{FSM}$			200		A
Non-repetitive avalanche energy at $T_J = 25\text{ °C}$ , $L = 100\text{ mH}$	$E_{AS}$			250		mJ
Peak repetitive reverse current at $t_p = 2\text{ }\mu\text{s}$ , 1 kHz, $T_J = 38\text{ °C} \pm 2\text{ °C}$ per diode	$I_{RRM}$			1.0		A
Isolation voltage (ITO-220AB only) from terminal to heatsink $t = 1\text{ min}$	$V_{AC}$			1500		V
Operating junction and storage temperature range	$T_J, T_{STG}$			- 55 to + 150		°C

# VT3080S, VFT3080S, VBT3080S, VIT3080S

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ELECTRICAL CHARACTERISTICS (T <sub>A</sub> = 25 °C unless otherwise noted)						
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT
Breakdown voltage	I <sub>R</sub> = 1.0 mA	T <sub>A</sub> = 25 °C	V <sub>BR</sub>	80 (minimum)	-	V
Instantaneous forward voltage	I <sub>F</sub> = 5 A	T <sub>A</sub> = 25 °C	V <sub>F</sub> <sup>(1)</sup>	0.47	-	V
	I <sub>F</sub> = 15 A			0.61	-	
	I <sub>F</sub> = 30 A			0.82	0.95	
	I <sub>F</sub> = 5 A	T <sub>A</sub> = 125 °C		0.39	-	
	I <sub>F</sub> = 15 A			0.57	-	
	I <sub>F</sub> = 30 A			0.73	0.82	
Reverse current	V <sub>R</sub> = 80 V	T <sub>A</sub> = 25 °C	I <sub>R</sub> <sup>(2)</sup>	70	1000	μA
		T <sub>A</sub> = 125 °C		23	45	mA

**Notes**

- (1) Pulse test: 300 μs pulse width, 1 % duty cycle
- (2) Pulse test: Pulse width ≤ 40 ms

THERMAL CHARACTERISTICS (T <sub>A</sub> = 25 °C unless otherwise noted)						
PARAMETER	SYMBOL	VT3080S	VFT3080S	VBT3080S	VIT3080S	UNIT
Typical thermal resistance	R <sub>θJC</sub>	1.5	5.0	1.5	1.5	°C/W

ORDERING INFORMATION (Example)					
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE
TO-220AB	VT3080S-E3/4W	1.88	4W	50/tube	Tube
ITO-220AB	VFT3080S-E3/4W	1.75	4W	50/tube	Tube
TO-263AB	VBT3080S-E3/4W	1.37	4W	50/tube	Tube
TO-263AB	VBT3080S-E3/8W	1.37	8W	800/reel	Tape and reel
TO-262AA	VIT3080S-E3/4W	1.46	4W	50/tube	Tube

## RATINGS AND CHARACTERISTICS CURVES

(T<sub>A</sub> = 25 °C unless otherwise noted)

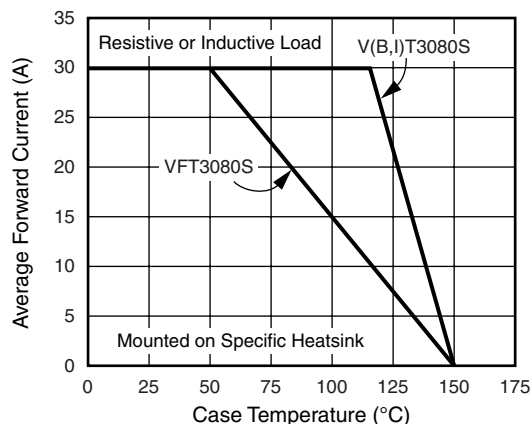


Fig. 1 - Forward Current Derating Curve

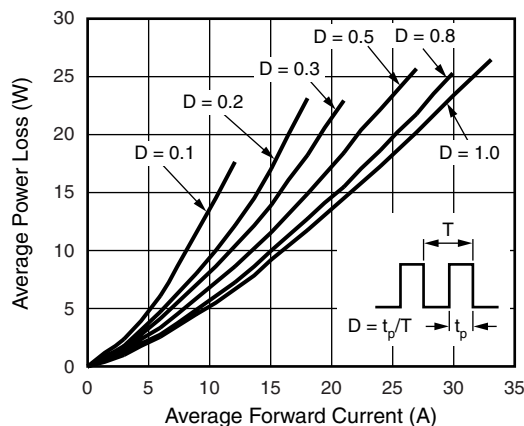


Fig. 2 - Forward Power Loss Characteristics

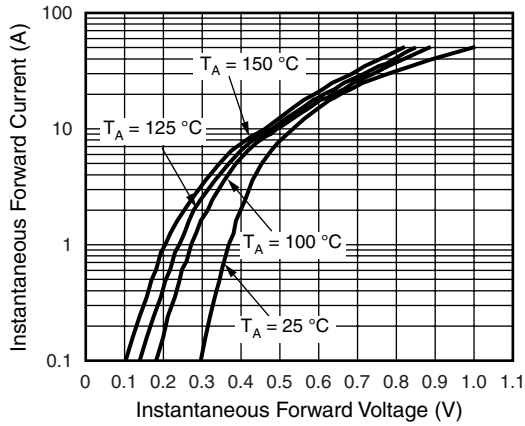


Fig. 3 - Typical Instantaneous Forward Characteristics

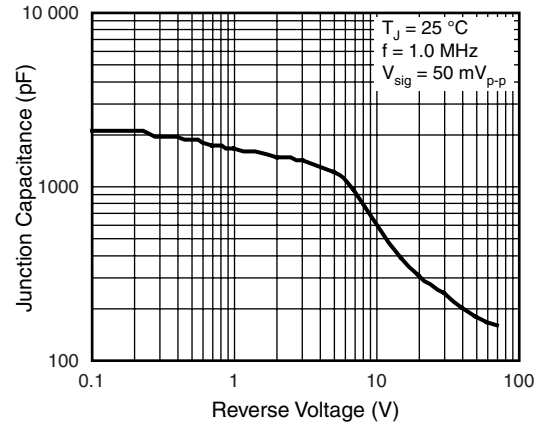


Fig. 5 - Typical Junction Capacitance

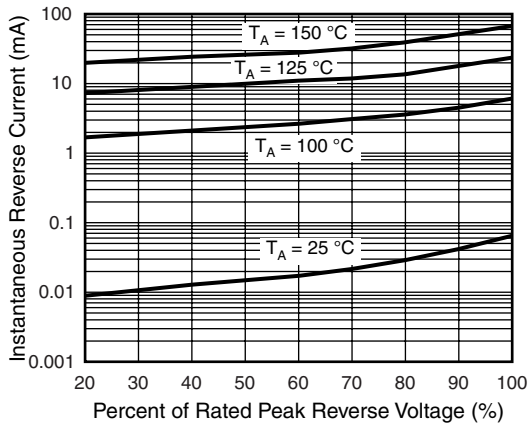


Fig. 4 - Typical Reverse Characteristics

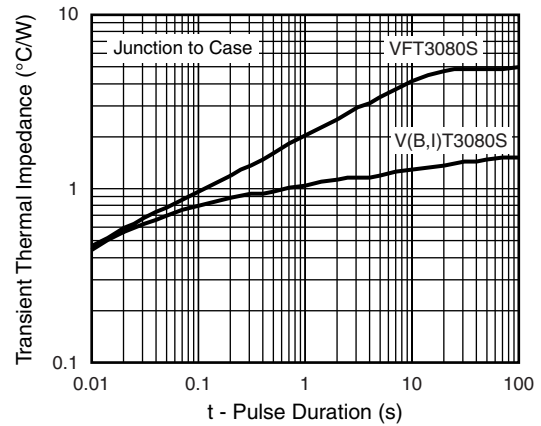


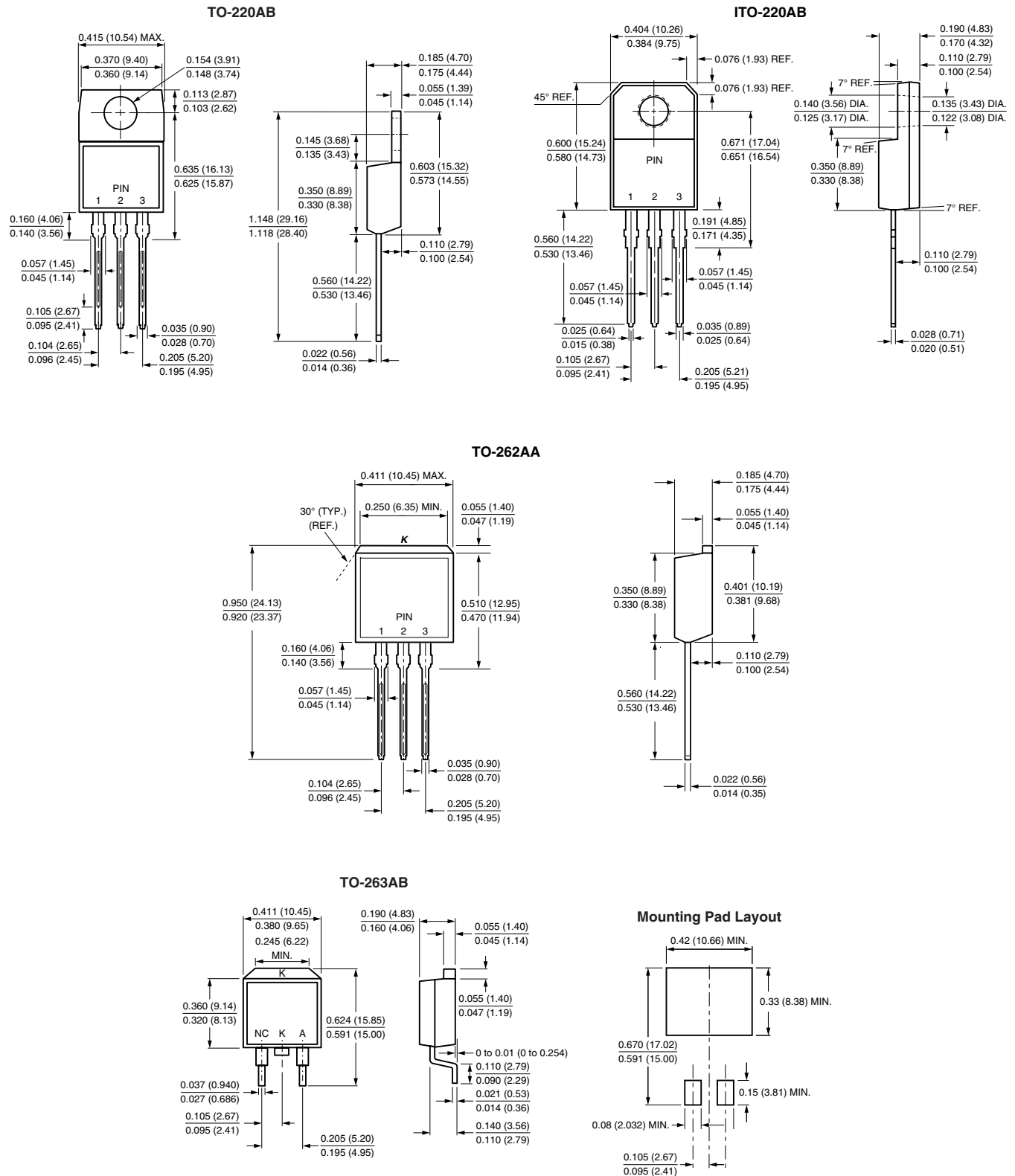
Fig. 6 - Typical Transient Thermal Impedance

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## PACKAGE OUTLINE DIMENSIONS in inches (millimeters)





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